

## 16CTQ200 16CTQ200S 16CTQ200-1

#### Technical Data Data Sheet N0668, Rev. A

RoHS 🗭

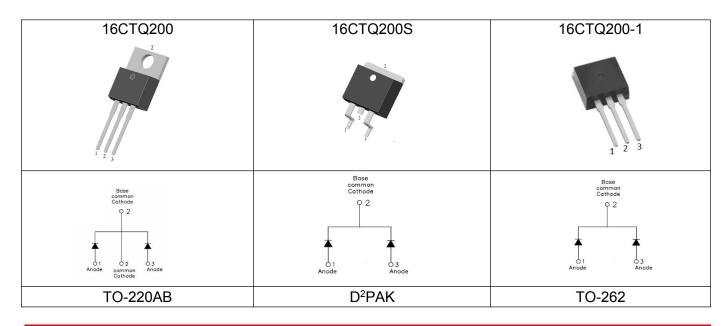
# 16CTQ200/16CTQ200S /16CTQ200-1 SCHOTTKY RECTIFIER

### Features

- 175°C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection



### Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	200	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=154°C, rectangular wave form	8(Per Leg) 16(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>c</sub> = 25 °C	330	А

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## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 8A, Pulse, T <sub>J</sub> = 25 °C	0.82	0.84	V
(Per Leg)*	V <sub>F2</sub>	@ 8A, Pulse, T <sub>J</sub> = 125 °C	0.68	0.70	V
Reverse Current (Per Leg)*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25 °C	0.0002	1.0	mA
	I <sub>R2</sub>	$@V_R = rated V_R$ T <sub>J</sub> = 125 °C	0.2	7.0	mA
Junction Capacitance(Per Leg)	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	260	300	pF
Typical Series Inductance (per leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300  $\mu s, \ duty \ cycle < 2\%$ 

### **Thermal-Mechanical Specifications:**

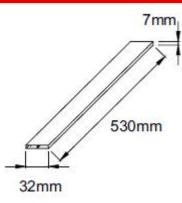
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	3.25	°C/W
Typical Thermal Resistance, Case to Heat Sink	R <sub>0JL</sub>	DC operation	0.50	°C/W
Case Style	TO-220AB D <sup>2</sup> PAK TO-262			

## **Tube Specification**

Device	Package	Weight	Shipping
16CTQ200	TO-220AB	1.8g	50pcs / tube
16CTQ200S	D <sup>2</sup> PAK	1.85g	800pcs / reel
16CTQ200-1	TO-262	1.85g	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## Tube Specification(TO-220AB/TO-262)



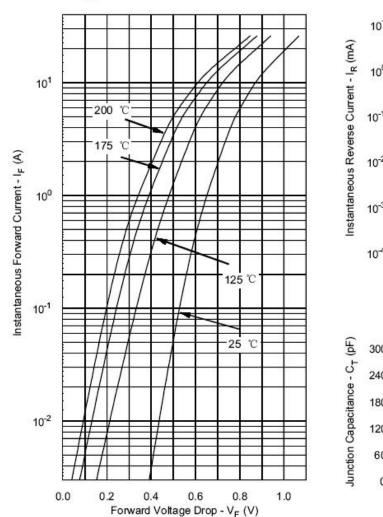


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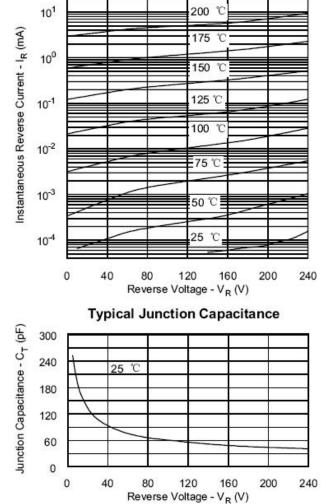
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### **Ratings and Characteristics Curves**



## Typical Forward Characteristics

#### **Typical Reverse Characteristics**

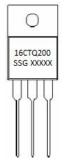


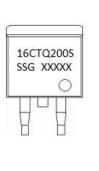


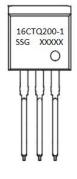
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## **Marking Diagram**







#### Where XXXXX is YYWWL

- = Forward Current (16A)
- = Configuration
- = Device Type
- = Reverse Voltage (200V) S/-1
  - = Package type
  - = SSG = Year

16

С

TQ

200

SSG

YΥ

WW

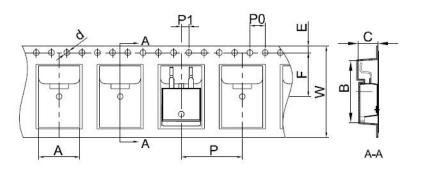
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= Week = Lot Number

Cautions: Molding resin

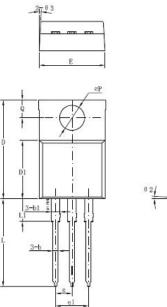
Epoxy resin UL:94V-0

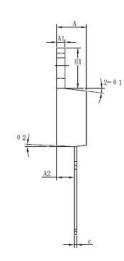
### **Carrier Tape Specification D<sup>2</sup>PAK**



Symbol	Millimeters		
	Min.	Max.	
A	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

#### **Mechanical Dimensions TO-220AB**





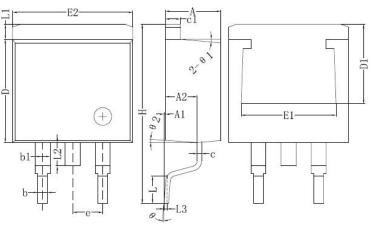
Symbol	Millimeters			
2,	Min.	Typical	Max.	
Α	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
е		2.54		
e1	4.98	5.06	5.18	
H1	6.04	6.24	6.44	
L	12.7	13.56	13.80	
L1	3.56	3.5	3.96	
ΦΡ	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4°		

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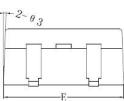
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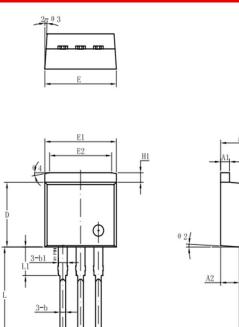
## Mechanical Dimensions D<sup>2</sup>PAK



Symbol	Millimeters			
2	Min.	Typical	Max.	
Α	4.47	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.50	8.70	8.90	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.31	
е		2.54		
н	14.6	15.1	15.6	
L	2.00	2.30	2.74	
L1	1.12	1.27	1.42	
L2	1.30		2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		<b>4</b> °		
e3		4°		



## **Mechanical Dimensions TO-262**



Symbol	Millimeters			
Symbol	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.55	8.70	8.85	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.18	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.70	
L1	1.17	1.27	1.40	
L2			2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		<b>4</b> °		
e3		4°		

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## 16CTQ200 16CTQ200S 16CTQ200-1





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